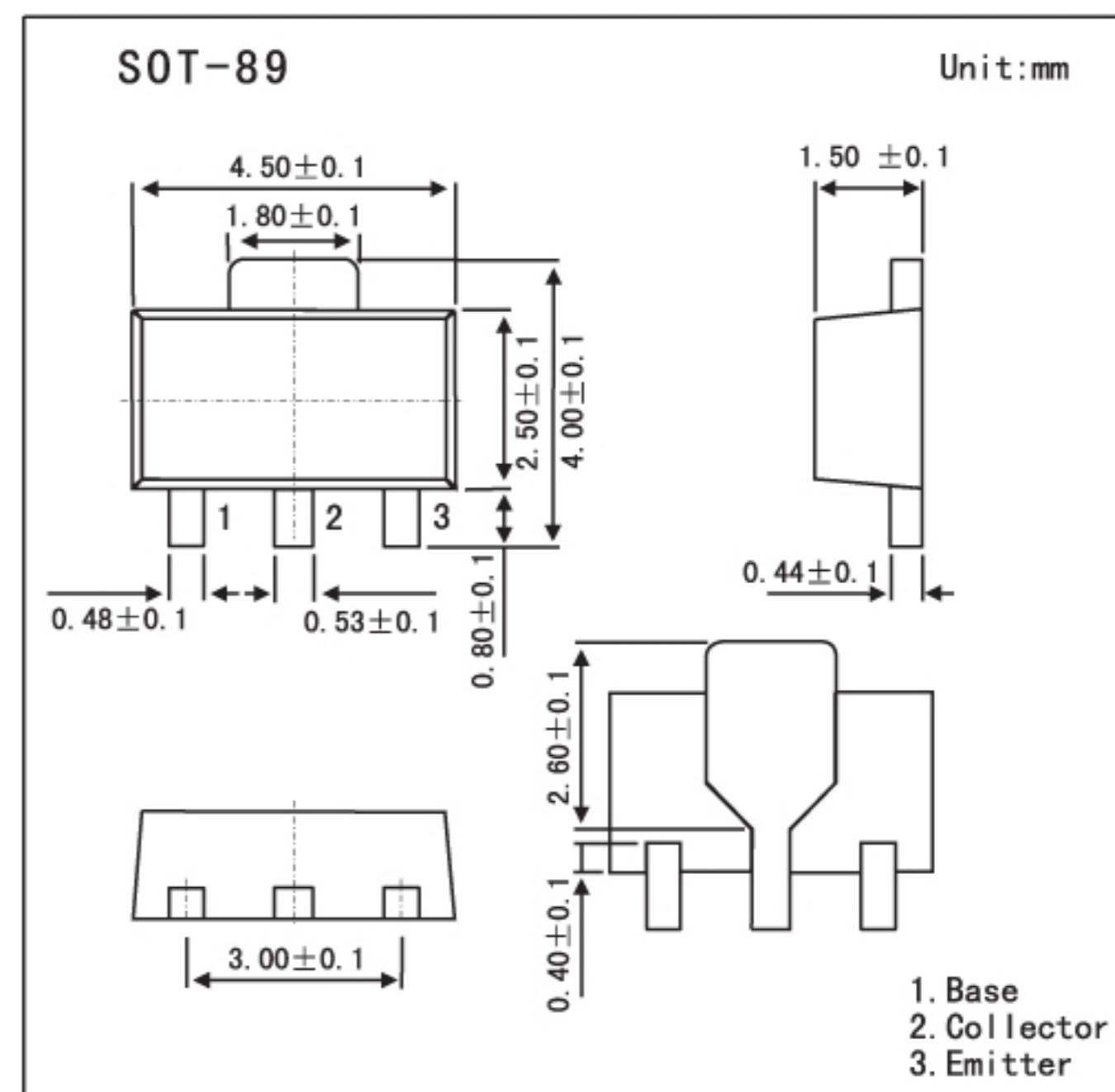


NPN Epitaxial Planar Silicon Transistors

■ Features

- High breakdown voltage. ($V_{CEO} = 400V$)
- Low saturation voltage,
- typically $V_{CE(sat)} = 0.05V$ at $I_C / I_B = 10mA / 1mA$.
- High switching speed, typically $t_f = 1.7\mu s$ at $I_C = 100mA$.



■ Absolute Maximum Ratings $T_a = 25^\circ C$

| Parameter | Symbol | Rating | Unit |
|----------------------------|-----------|------------|------|
| collector-base voltage | V_{CBO} | 400 | V |
| collector-emitter voltage | V_{CEO} | 400 | V |
| emitter-base voltage | V_{EBO} | 7 | V |
| collector current | I_C | 0.1 | A |
| | | 0.2 | A *1 |
| CollectorPower Dissipation | P_C | 0.5 | W *2 |
| | | 2 | W |
| Junotion Temperature | T_J | 150 | °C |
| storage Temperature | T_{stg} | -55 to 150 | °C |

*1 Single pulse $pw=20ms, Duty=1/2$

*2 When mounted on a 40X40X0.7 mm ceramic board.

■ Electrical Characteristics Ta = 25°C

| Parameter | Symbol | Testconditons | Min | Typ | Max | Unit |
|--------------------------------------|------------------|--|-----|------|-----|------|
| Collector-base breakdown voltage | Bvcbo | Ic=50µA | 400 | | | V |
| Collector-emitter breakdown voltage | Bvceo | Ic=1mA | 400 | | | V |
| Emitter-base breakdown voltage | Bvebo | Ie=50µA | 7 | | | V |
| Collector cutoff current | Icbo | Vcb=400V | | | 10 | µA |
| Emitter cutoff current | Ieb0 | Veb=6V | | | 10 | µA |
| Collector-emitter saturation voltage | Vce(sat) | Ic/Ib=10mA/1mA | | 0.05 | 0.5 | V |
| Base-emitter saturation voltage | Vbe(sat) | Ic/Ib=10mA/1mA | | | 1.5 | V |
| DC current transfer ratio | hFE | Vce=10V , Ic=10mA | 82 | | 270 | |
| Transition frequency | fT | Vce=10V , Ie=-10mA , f=10MHz | | 20 | | MHz |
| Output capacitance | Cob | Vcb=10V , Ie=0A , f=1MHz | | 7 | | pF |
| Turn-on time | t _{on} | Ic=-100mA RL=1.5kΩ Ib1=-Ib2=10mA Vcc=-150V | | 1 | | ns |
| Storage time | t _{stg} | | | 5.5 | | ns |
| Fall time | t _f | | | 1.7 | | ns |

■ hFE Classification

| TYPE | CEP | CEQ |
|---------|-----------|------------|
| Rank | P | Q |
| Marking | 82 to 180 | 120 to 270 |

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